IGBT nomenclature

**Device type**
- **G** = IGBT

**Technology**
- **4** = Gen 4
- **Blank** = Gen 3

**Die combination**
- **M** = IGBT + diode
- **Blank** = IGBT only

**Package type**
- **C** = Chip
- **I** = TO-259
- **M** = TO-254
- **V** = TO-258

**Voltage**
- **C** = 600V
- **H** = 1200V

**Lead option**
- **A** = Lead form down*
- **B** = Lead form up
- **C** = Lead trimmed (clipped)
  *Lead attach if package is SMD

**Screening level**
- **SCX** = TXlevel
- **SCV** = TXV level
- **SCS** = Space level

**Speed**
- **U** = Ultra fast
- **F** = Fast
- **S** = Standard

**Voltage variant**

**Die size**
- **3** = Die size 3
- **4** = Die size 4
- **5** = Die size 5